# New Jersey Semi-Conductor Products, Inc.

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## 1N4938

### SILICON POLARITY SWITCHING DIODE

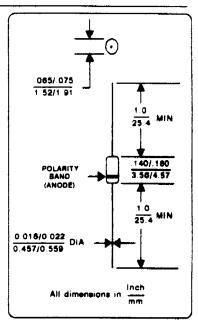
#### **ABSOLUTE MAXIMUM RATINGS**

| YMBOL             | CHARACTERISTIC                       | VALUE       | UNIT           |
|-------------------|--------------------------------------|-------------|----------------|
| V <sub>o</sub>    | Reverse Voltage                      | 175         | ٧              |
| Vem               | Peak Reverse Voltage                 | 200         | V              |
| i <sub>o</sub>    | Rectified Current (Average)          | 100(1)      | mA             |
|                   | Half Wave Rectification With         |             |                |
|                   | Resistive Load                       |             |                |
|                   | at TA = 250C and f≥50 Hz             |             |                |
| I <sub>F SW</sub> | Surge Current at t=1 ms and T,=25 °C | 2.0         | A              |
| Ρ                 | Power Dissipation at TA = 25 OC      | 500(1)      | m W            |
| T,                | Maximum Junction Temperature         | 200         | ٥C             |
| Ť,                | Storage Temperature                  | -85 to +175 | <sup>3</sup> C |

#### ELECTRICAL CHARACTERISTICS @ 152 1, unless otherwise specified

| SYMBOL          | CHARACTERISTIC                                | MIN | MAX     | UNITS      | TEST CONDITIONS   |
|-----------------|---|-----|---------|------------|---|
| <b>V</b> r      | Forward Voltage                               |     | 1 0     | Voits      | t <sub>e</sub> = 100 mA   |
| l <sub>a</sub>  | Reverse Current                               |     | 0 1 100 | nA<br>nA   | V <sub>n</sub> = 175 Volts <b>②</b> T <sub>i</sub> = 25°C<br>V <sub>n</sub> = 175 Volts <b>②</b> T <sub>i</sub> = 150°C |
| V چوره          | Reverse Breakdown Voltage                     | 200 |         | Voits      | i <sub>sean</sub> ⇒ 100 uA pulses   |
| C. ,.           | Capacitance                                   |     | 5       | ρF         | V, = Vn = 0   |
| t.              | Reverse Recovery Time                         |     | 50      | п <b>8</b> | from I <sub>c</sub> =10 mA to I <sub>n</sub> =1 mA,<br>V <sub>a</sub> = 6 V, R <sub>i</sub> = 100 ohrns                 |
| A <sub>.A</sub> | Thermal Resistance<br>Junction to Ambient Air |     | 0.350   | K/mW       |   |
| n۷              | Rectification Efficiency                      | 45  |         |            | f=100 MHz. Var=2 V  |

NOTE 1 Valid provided that leads are kept at ambient temperature at a distance of 6 mm (32") from case



#### DO-35 OUTLINE

#### **DESIGN DATA**

CASE: Hermetically sealed glass case. DO-35 Outline.

LEAD MATERIAL: Copper Clad Stee-

LEAD FINISH: Tin Plate

THERMAL RESISTANCE:
250 °C/w (Typical)
junction to ambient.

POLARITY: Diode to be operated with the banded (cathode) and positive with respect to the opposite end

WEIGHT: 0.14 Grams

MOUNTING POSITION: Any



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